Synthesis of a one-dimensional atomic crystal of vanadium selenide (V$_2$Se$_9$)$^\dagger$

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The synthesis and nanoscale dispersion of a new one-dimensional (1D) material, V$_2$Se$_9$, in which chain-shaped molecular units with strong covalent bonds are assembled in a crystal structure via weak van der Waals attraction between chains, were successfully carried out. V$_2$Se$_9$ is synthesized by solid-state reaction and additional heat treatment. The synthesized V$_2$Se$_9$ has excellent thermal stability up to 400 °C and has been experimentally confirmed to be dispersed up to ~20 nm or less through a specific solvent dispersion. The covalently bonded V$_2$Se$_9$ chain, when isolated from its bulk material, is expected to exhibit unique quantum physical properties owing to the confinement of electrons in the 1D chain structure and the absence of inter-chain interactions, as demonstrated in the case of graphene and other 2D materials. Therefore, the novel 1D material of V$_2$Se$_9$, as an extension of the current 2D material, is expected to create a new class of materials that will be of significant interest to the materials science and nanotechnology communities for new device applications.

Introduction

Scaling down or size-reduction has been one of the important aspects of modern science and technology for the development of devices with higher performance. To overcome the problems of existing materials occurring in nano-size, there has been a paradigm shift in research towards low-dimensional (2D and 1D) materials. Unlike the nanomaterials obtained by merely reducing the size of bulk materials, low-dimensional materials present new quantum-physical characteristics and excellent electrical, optical, and mechanical properties.$^1$–$^9$

Among the 2D materials, graphene exhibits excellent carrier mobility, but does not have the bandgap necessary for the fabrication of reliable semiconductor devices.$^{10}$ Other 2D semiconductor materials, such as transition metal dichalcogenides (TMDCs) and black phosphor, have appropriate bandgaps (1–2 eV), but their stability and/or carrier mobility are limited.$^{11}$–$^{11}$ More importantly, decreased transport properties at the nanoscale are still unavoidable in current 2D materials, because they have dangling bonds at the side edges and domain boundaries.$^{14}$ Carbon nanotubes (CNTs, representative 1D materials), which exhibit high electrical mobility, chemical stability, and mechanical strength, have been extensively studied for use as building blocks of transistors, sensors, and nanocomposites.$^{15}$–$^{17}$ However, the wide range of electronic structures that arise from the different chirality of CNTs hinders the fabrication of nanoelectronic devices with uniform performance. Therefore, it is necessary to either achieve separation of single-chirality CNTs from bulk CNTs or control the chirality during the growth of CNTs.$^{18}$ Although several studies have addressed these issues, it is still challenging to obtain single-chirality CNTs.

To overcome the problems of existing low-dimensional materials, researches on new 1D materials have been carried out. For example, extensive studies for bulk synthesis and atomic scale dispersion of LiMo$_3$Se$_3$ and Mo$_9$S$_6$–I$_x$ have been reported.$^{19}$–$^{32}$ Recently, quantum confinement effect of LiMo$_5$–Se$_3$ and bio-stability of Mo$_9$S$_6$–I$_x$ were demonstrated and their applications have been explored.$^{24}$–$^{35}$ In addition, device application using new 1D materials, such as Sb$_2$Se$_4$ (optoelectronic devices using the property of effectively reducing exciton decay because of absence of dangling bonds) and VS$_4$
(electrochemical energy storage using the space between 1D nanostructures) have been reported.\textsuperscript{24–36} Therefore, there is a definite scope for identification, synthesis, and characterization of new 1D materials.

By understanding the mechanism by which 1D materials form a 3D structure, new 1D materials can be discovered for potential applications. As the interlayer coupling energy of 2D materials is categorized into van der Waals (vdW) bonding and electrostatic bonding, the above-mentioned new 1D materials can also be classified accordingly: vdw bonding in Sb\textsubscript{2}Se\textsubscript{3}, Mo\textsubscript{6}S\textsubscript{9}–I\textsubscript{2}, and VS\textsubscript{4} and electrostatic bonding by intercalated Li\textsuperscript{+} in LiMo\textsubscript{3}Se\textsubscript{3}. In the case of cation intercalated 1D materials, cations are separated in the process of dispersion,\textsuperscript{24} leaving a local negative charge defect on the surface of the 1D materials.\textsuperscript{19–23} On the other hand, in the case of vdW bonding, it is advantageous to obtain a high-purity 1D atomic crystal without surface defects using an appropriate synthesis process. Among the 1D materials with vdw type bonds, the synthesis, dispersion, and basic properties of Mo\textsubscript{6}S\textsubscript{9}–I\textsubscript{2} have been studied to a relatively significant degree.\textsuperscript{26–29,31–33} However, the crystal structure of Mo\textsubscript{6}S\textsubscript{9}–I\textsubscript{2} has not been well-defined since the positions of sulfur and iodine atoms bridged to molybdenum atoms may vary even in the same stoichiometric composition. In addition, the thermodynamic information of the ternary system (Mo, S, and I) is also lacking, which makes it difficult to understand the physical properties of Mo\textsubscript{6}S\textsubscript{9}–I\textsubscript{2}.\textsuperscript{30}

In this study, we have synthesized a new 1D bulk material with a binary system and well-defined crystal structure, V\textsubscript{2}Se\textsubscript{9}, in which chain-shaped molecular units with strong covalent bonds are assembled in a crystal structure via weak vdw attraction between chains. In addition, 1D materials with an inorganic molecular chain structure and dangling bond-free surface were obtained as a single-chain atomic crystal from a 3D bulk solid by the dispersion based exfoliation method (see Fig. 1a).

**Results and discussion**

As shown in the phase diagram in Fig. 1b, vanadium, transition metal with an outermost 3d orbital, can bond with selenium in various compositions (from V\textsubscript{2}Se\textsubscript{4} to V\textsubscript{2}Se\textsubscript{9}). Therefore, to synthesize a stoichiometric V\textsubscript{2}Se\textsubscript{9} compound, the V : Se ratio and the synthesis temperature need to be carefully considered.

![Fig. 1](image-url) (a) Crystal structure of V\textsubscript{2}Se\textsubscript{9} and schematic illustration of the V\textsubscript{2}Se\textsubscript{9} dispersion. (b) Phase diagram of V–Se binary system.

When the synthesis of V and Se powders in solid form is carried out at an exact atomic mixing ratio of 2 : 9, an unwanted phase (V\textsubscript{2}Se\textsubscript{12}) can be formed at the specific interface owing to fluctuations in the V : Se ratio. Therefore, in this study, the experiment was carried out under excess Se conditions (V : Se ratio of 2 : 12.6). The experimental results obtained for the exact stoichiometric ratio of 2 : 9 are shown in Fig. S2.\textsuperscript{†}

The results of X-ray diffraction (XRD) analysis of the samples synthesized at different temperatures (Fig. 2a) indicate that the V\textsubscript{2}Se\textsubscript{9} phase is formed at temperatures below 330 °C, whereas the V\textsubscript{2}Se\textsubscript{12} phase is formed at temperatures above 360 °C (mixed phase at 340 °C). Scanning electron microscopy (SEM) and energy dispersive spectroscopy (EDS) were performed to analyze the structure and the composition of the materials synthesized at three specific temperatures (330, 340, and 380 °C). Using the results of XRD and EDS composition analysis, it is possible to determine the composition of the microstructural region at each temperature (Fig. 2b and S2)\textsuperscript{†}. The V\textsubscript{2}Se\textsubscript{9} phase appears at 380 °C and shows a layered lamellar structure, which is similar to the previously reported structure of TMDCs.\textsuperscript{37} The V\textsubscript{2}Se\textsubscript{12} phase, which appears at temperatures ≤ 340 °C, exhibits a 3D structure. However, as can be seen from the SEM images at 340 °C, a part of the V\textsubscript{2}Se\textsubscript{12} phase begins to partially disperse into a 1D structure like a thread. Furthermore, Se, which is observed at all temperatures, is dispersed in several places in the form of particles; Se can be removed by heat treatment at its sublimation temperature (>221 °C).\textsuperscript{38}

The remaining Se particles can be removed by sublimation (heat treatment in a tube furnace at 250 °C under Ar atmosphere for 24 h). It is evident from the XRD pattern (Fig. 3a) that, Se with hexagonal crystals in the solid state can be completely removed after sublimation, and the V\textsubscript{2}Se\textsubscript{9} solid crystal is exposed at the site where Se is sublimated (Fig. 3b). The thermal stability and the residual Se sublimation of V\textsubscript{2}Se\textsubscript{9} were confirmed by thermogravimetric characterization using differential thermal analysis (DTA) and thermogravimetric analysis (TGA) (Fig. 3c and d). Before Se sublimation treatment, the mass decrease was about 68.1%, while that after Se sublimation...
The residual-Se sublimated $V_2Se_9$ was dispersed into a 1D chain and its characteristics were analyzed. Bulk $V_2Se_9$ was dispersed in isopropyl alcohol (IPA) solvent and deposited on Si/SiO$_2$ wafer after sonication. As shown in Fig. 4a, a distinctive Tyndall effect appears, indicating nanoscale dispersion. The dispersed $V_2Se_9$ in IPA were spin-coated on Si/SiO$_2$ substrates, and the size of the nano-chain was analyzed using an atomic force microscope (AFM); the results are shown in Fig. 4b. It is evident that the 1D structure of $V_2Se_9$ chains with an average size of 16 nm is well dispersed. IR absorption spectrum of dispersed solution is given in Fig. S3.† The IR absorption peak is observed at 1700 nm which correspond to the known bandgap of 0.73 eV (Fig. S3†). Transmission electron microscopy (TEM) results also confirm that the 1D chain of size 16 nm exhibits a high degree of crystallinity and is well separated (Fig. 4c). It is considered that more detailed separation of 1D $V_2Se_9$ chains into atomic units will require optimization of the dispersion solvent and the dispersion process.

**Experimental section**

**Synthesis**

Vanadium selenide ($V_2Se_9$) was synthesized using V (powder, −325 mesh, 99.5%, Aldrich) and Se (powder, 99+%, Alfa Aesar) elements. The mixture of V (0.2038 g) and Se (1.4213 or 1.9898 g for V : Se ratio of 2 : 9 or 2 : 12.6) was pelletized and then sealed in a 10 cm-long evacuated quartz tube. The quartz ampoule was heated for 120 h at a temperature of 300–400 °C (at 5.5 °C h$^{-1}$) and then cooled (at 10 °C h$^{-1}$). The resulting material was a dark gray sintered powder (right inset, Fig. 2a). The unreacted Se was sublimated in a tube furnace at 250 °C under Ar atmosphere for 24 h.
Dispersion

Two milligrams of V₂Se₉ were dispersed in 20 mL of IPA by ultrasonication. The ultrasonication was implemented by probe sonication (VC 505, Sonics & Materials, Inc.) for 5 min at a 2 s on/2 s off interval in order to crush the chunk powders. Then, bath sonication was implemented (B200SS-58K, 68 kHz, 200 W, KODO Technical) for 3 h to exfoliate the crushed bulk V₂Se₉ into nanochain as well as prevent the damage from probe sonication. After ultrasonication, centrifugation at 6000 rpm for 10 min was carried out to remove the insufficiently dispersed chains. Five milliliters of the supernatant solution was used for AFM and TEM analyses.

Characterization

Powder XRD (Mac Science, M18XHF22) was performed using Cu-Kα radiation (λ = 0.154 nm). A field-emission scanning electron microscope (FESEM, Hitachi, S-4300SE) and EDS attached to FESEM was employed for morphology and composition analysis. Thermal gravimetry differential thermal analysis (TG-DTA, Seiko Instrument Inc., TG/DTA7300) measurements were performed under N₂ atmosphere up to 1200 °C (at 10 °C min⁻¹). Atomic force microscopy (AFM, Park systems,XE100 & XE150) was operated in non-contact mode; the samples were prepared by spin coating on Si/SiO₂ wafer. UV-vis-NIR spectroscopy (Agilent Technologies, CARY-5000) was employed for the optical property analysis. An aberration-corrected scanning transmission electron microscope (STEM, JEOL, JEM ARM 200F) was operated at an acceleration voltage of 80 kV. The sample for STEM was prepared by drop casting on a graphene-coated Quantifoil TEM grid.

Conclusions

The synthesis and nanoscale dispersion of a new 1D material, V₂Se₉, which exhibits a molecular chain structure with a diameter up to ~1 nm, were successfully carried out. The reaction of V and Se was induced by the solid-state method to synthesize high purity V₂Se₉ crystals. The synthesized V₂Se₉ crystals were dispersed to obtain 1D nanochains with a size of 16 nm or less. The covalently bonded V₂Se₉ chain, when isolated from its 3D bulk material, is expected to exhibit unique quantum physical properties owing to the confinement of electrons in the 1D chain structure and the absence of inter-chain interactions, as demonstrated in the case of graphene and other 2D materials. Therefore, the novel 1D material of V₂Se₉, as an extension of the current 2D material, is expected to create a new class of materials that will be of significant interest to materials science and nanotechnology communities for new device applications.

Author contribution

J. Y. C. designed the experiments, and S. O. and S. C. performed the chemical reaction experiments and B. J. K. and K. H. C. supported the elemental analysis. J. J. and Y. H. support the chemical reaction experiment and D. K. and W. S. J. and Y. M. K. supported structural analysis. H. K. Y. and J. Y. C. conceived and supervised this study and provided intellectual and technical guidance. This journal is © The Royal Society of Chemistry 2018

Conflicts of interest

There are no conflicts to declare.

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